

CBM-120

Mosaic Array Series

Ultraviolet Chip On Board LEDs





Table of Contents

| Technology Overview2 |
|--|
| Ordering Information3 |
| Binning Structure4 |
| Ordering Bin Kits 5 |
| Optical & Electrical Characteristics |
| Typical Spectrum8 |
| Angular Distribution8 |
| Reliability Data9 |
| Thermal Resistance 10 |
| Electrical Pinout (C31) 10 |
| Mechanical Dimensions Square Package (C31) 11 |
| Mechanical Dimensions Slim Package (C14) 12 |
| Shipping Tray Square Package (C31) |
| Shipping Tray Slim Package (C14)14 |
| Packaging Specifications . 15 |
| Revision History16 |

Features:

- Mosaic Array UV LED chipset with surface emitting area of 12 mm², 4:3 aspect ratio
- All the benefits of chip on board processing without the need for complicated assembly process
- Vertical chip UV LED technology for high power density and uniform emission
- Wide Range of UVA Wavelengths
- High thermal conductivity copper coreboard package
- Low-profile window for efficient coupling into small-etendue systems
- Can be operated at variable drive currents up to 18A
- NIST traceable optical and electrical measurement testing
- Environmentally friendly: RoHS and Halogen compliant

Applications:

- Curing:
 - > Inks
 - > Coatings
 - > Adhesives
- Inspection
- Machine Vision

- Fiber-coupled illumination
- Specialty Projection Systems for Maskless Lithography
- Rapid Prototyping and 3D printing
- Medical and Scientific Instrumentation





Technology Overview

Luminus LEDs benefit from innovations in device technology, chip packaging and thermal management. This suite of technologies give engineers and system designers the freedom to develop solutions both high in power and efficiency.

Luminus Mosaic Array LED Technology

Luminus' Devices vertical chip technology enables LED chips with uniform brightness over the entire chip surface. The optical power and brightness produced by these densely packed arrays of devices enable solutions not possible with single chip packages that be used to replace arc and halogen lamps.

Packaging Technology

Thermal management is critical in high power LED applications. With a thermal resistance from junction to heat sink of 0.6 °C/W, Luminus CBM-120 LEDs have the lowest thermal resistance of any UV LED on the market. This will allow the LEDs to be driven at higher current densities while maintaining a low junction temperature, thereby resulting in brighter solutions and longer lifetimes.

Reliability

With designs based on years of chip and packaging development experience, Luminus LEDs are one of the most reliable light sources in the world today. Luminus LEDs pass a rigorous suite of environmental and mechanical stress tests, including mechanical shock, vibration, temperature cycling and humidity, and have been fully qualified for use in extreme high power and high current applications. With very low failure rates and median lifetimes that can exceed 30,000 hours, Luminus UV LEDs are ready for even the most demanding applications.

Environmental Benefits

Luminus LEDs help reduce power consumption and the amount of hazardous waste entering the environment. All LED products manufactured by Luminus are RoHS and Halogen compliant and free of hazardous materials, including lead and mercury.

Understanding Mosaic Array UV LED Test Specifications

Every Luminus LED is fully tested to ensure that it meets the high quality standards expected from Luminus' products.

Testing Temperature

Luminus core board products are typically measured in such a way that the characteristics reported agree with how the devices will actually perform when incorporated into a system. This measurement is accomplished by mounting the devices on a 40°C heat sink and measuring the device while fully powered.

This method of measurement ensures that Luminus LEDs perform in the field just as they are specified.

Multiple Operating Points

The tables on the following pages provide typical optical and electrical characteristics for the standard drive conditions. Since the LEDs can be operated over a wide range of drive conditions (currents from 200 mA to 18 A, and duty cycle from <1% to 100%) there are many other potential values attainable. Driving devices beyond recommended driving conditions shortens lifetime.



Ordering Information

| Products | Ordering Part Number | Description | |
|------------|---|--|--|
| CDM 120 UV | CBM-120-UV-C31-FF##-2# CBM-120 Mosaic Array UV chipset consisting of 12x1mm2 UV thermistor, connectors, and a square copper-core PCB. | | |
| CBM-120-UV | CBM-120-UV-C14-FF###-2# | CBM-120 Mosaic Array UV chipset consisting of 12x1mm2 UV LEDs, connectors, and a slim (rectangular) copper-core PCB. | |

Part Number Nomenclature

CBM — 120 — CC — C## — FF###-2#

| Product Family | Chip Area | Color | Package Configuration | Bin Kit 1,2 |
|---|-------------|------------------|---|--|
| CBM: Copper- core PCB, Mosiac Array | 120: 12 mm² | UV = Ultraviolet | C14: 44.5 mm x 10 mm - Slim Package C31: 28 mm x 26.75 mm - Square Package See Mechanical Drawing section | See page 5 for complete bin definition table |

Note 1: A Bin Kit represents a group of individual flux or power bins that are shippable for a given ordering part number. Individual flux bins are not orderable..

Note 2: Flux Bin listed is minimum bin shipped - higher bins may be included at Luminus' discretion



CBM-120-UV Binning Structure

CBM-120-UV LEDs are specified for luminous flux and chromaticity/wavelength at a drive current of 9 A (750 mA/mm2) and placed into one of the following Power Bins and Wavelength Bins:

Power Bins³

| Color | Power Flux Bin (FF) | Minimum Flux (W) | Maximum Flux (W) |
|-------|---------------------|------------------|------------------|
| | FA | 6.0 | 6.5 |
| | FB | 6.5 | 7.0 |
| | GA | 7.0 | 7.5 |
| | GB | 7.5 | 8.0 |
| UV | Н | 8.0 | 9.1 |
| | Ι | 9.1 | 10.0 |
| | J | 10.0 | 11.0 |
| | K | 11.0 | 12.1 |
| | L | 12.1 | 13.3 |

Note 3: Luminus maintains a +/- 6% tolerance on power measurements.

Peak Wavelength Bins

| Color | Wavelength Bin (###) | Minimum Wavelength (nm) | Maximum Wavelength (nm) |
|-------|----------------------|-------------------------|-------------------------|
| | 365 | 365 | 370 |
| UV | 370 | 370 | 375 |
| | 375 | 375 | 380 |
| | 380 | 380 | 385 |
| | 385 | 385 | 390 |
| | 390 | 390 | 395 |
| | 395 | 395 | 400 |
| | 400 | 400 | 405 |
| | 405 | 405 | 410 |



CBM-120 UV Mosaic Array Bin Kits

| | Lumino | ous Flux | | Ordering |
|----------------------|----------------------|-----------|-----------------|----------------|
| Wavelength Range | Bin Kit Flux Code | Min. Flux | Wavelength Bins | Bin Kit Number |
| | FA | 6.0 | 365 | FA365-21 |
| | FA | 0.0 | 365, 370 | FA365-22 |
| 265 275 | FD | 6.5 | 365 | FB365-21 |
| 365-375 | FB | 6.5 | 365, 370 | FB365-22 |
| | C.A. | 7.0 | 365 | GA365-21 |
| | GA | 7.0 | 365, 370 | GA365-22 |
| | | | 380 | J380-21 |
| | J | 10.0 | 385 | J385-21 |
| 380-390 | | | 380, 385 | J380-22 |
| 380-390 | | 11.0 | 380 | K380-21 |
| | К | | 385 | K385-21 |
| | | | 380, 385 | K380-22 |
| | J | 10.0 | 390 | J390-21 |
| | | | 395 | J395-21 |
| 390-400 | | | 390, 395 | J390-22 |
| 3 90-4 00 | | | 390 | K390-21 |
| | К | 11.0 | 395 | K395-21 |
| | | | 390, 395 | K390-22 |
| | | | 400 | J400-21 |
| | J | 10.0 | 405 | J405-21 |
| 400 410 | | | 400, 405 | J400-22 |
| 400-410 | | | 400 | K400-21 |
| | К | K 11.0 | 405 | K405-21 |
| | | | 400, 405 | K400-22 |



Reference Optical & Electrical Characteristics ($T_{hs} = 40$ °C) ^{4,5}

| UV | | | | | | | | | |
|-----------------------|--|-----------|------|------|------------------|--------|------|------|-------|
| Parameter | Symbol | | | Valu | ies _e | | | | Unit |
| Peak Wavelength Range | λ | 365 - 375 | 380- | -390 | 390 | -400 | 400- | -410 | nm |
| Drive Conditions 7 | 1 | 9.0 | 9 | .0 | 9 | .0 9.0 | | .0 | Α |
| Peak Wavelength Typ. | $\lambda_{_{p}}$ | 368 | 384 | 387 | 393 | 397 | 403 | 407 | nm |
| Current Density | j | 0.75 | 0. | 75 | 0.75 | | 0.75 | | A/mm² |
| | $V_{_{Fmin}}$ | 3.0 | 3 | .0 | 3 | .0 | 3. | .0 | V |
| Forward Voltage | ard Voltage V_F 3.6 3.6 3.6 V_{Fmax} 4.0 4.0 4.0 | | 3 | .6 | 3.6 | | 3.6 | | V |
| | | | 4.0 | | V | | | | |
| Radiometric Flux 8 | $oldsymbol{\Phi}_{_{typ}}$ | 6.8 | 10.5 | | 10.5 | | 10.5 | | W |
| FWHM at 50% of Φ | Δλ _{1/2} | 14 | 1 | 4 | 1 | 4 | 1 | 4 | nm |

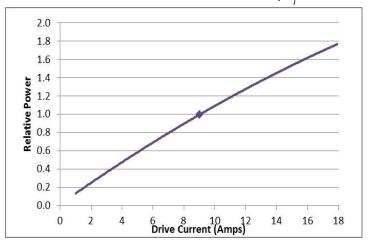
| Parameter | Symbol | Values | Unit |
|---|------------|--------------------------------|---------|
| Absolute Minimum Current (CW or Pulsed) 9 | | 0.2 | Α |
| Absolute Maximum Current (CW) 10 | | 365nm - 12 380nm-410nm - 18 | А |
| Absolute Maximum Surge Current ¹⁰ (Frequency > 240 Hz, duty cycle =10%, t=1ms) | | 30 | А |
| Maximum Junction Temperature 11 | T_{jmax} | 100 °C | |
| Storage Temperature Range | | -40 to +100 | °C |
| Emitting Area | | 12.9 | mm² |
| Emitting Area Dimensions | | 4.50 × 3.32 | mm × mm |

- Note 4: Data verified using NIST traceable calibration standard.
- Note 5: All data are based on test conditions with a constant heat sink temperature $T_{hs} = 40^{\circ}$ C under pulse testing conditions. Pulse conditions: 25% duty-cycle, frequency of 720Hz, 3 second soak.
- Note 6: Unless otherwise noted, values listed are typical. Devices are production tested and specified at 9 A.
- Note 7: Listed drive conditions are typical for common applications. CBM120-UV devices can be driven at currents ranging from 200 mA to 12A-18 A and at duty cycles ranging from 1% to 100%. Drive current and duty cycle should be adjusted as necessary to maintain the junction temperature desired to meet application lifetime requirements.
- Note 8: Typical total flux from emitting area at listed peak wavelength. Reported performance is included to show trends for a selected power level. For specific minimum and maximum values, use bin tables. For product roadmap and future performance of devices, contact Luminus.
- Note 9: Special design considerations must be observed for operation under 1 A. Please contact Luminus for further information.
- Note 10: CBM-120-UV LEDs are designed for operation to an absolute maximum current as specified above. Product lifetime data is specified at recommended forward drive currents. Sustained operation at or beyond absolute maximum currents will result in a reduction of device life time compared to recommended forward drive currents. Actual device lifetimes will also depend on junction temperature. Refer to the lifetime derating curves for further information. In pulsed operation, rise time from 10-90% of forward current should be longer than 0.5 µseconds.
- Note 11: Lifetime dependent on LED junction temperature. Input power and thermal system must be properly managed to ensure lifetime.

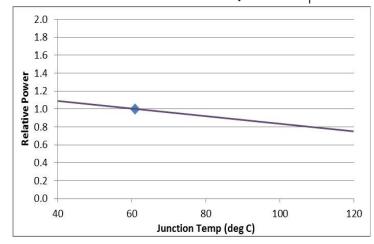


Optical & Electrical Characteristics

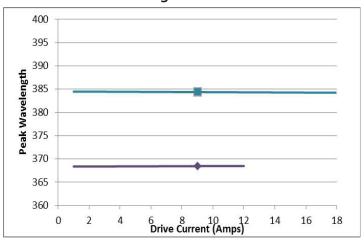
Relative Power vs Forward Current, T = 60°C



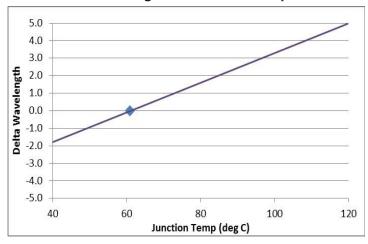
Relative Power vs Junc. Temperature, $I_r = 9 \text{ A}$



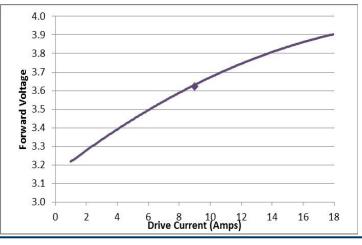
Peak Wavelength vs Forward Current



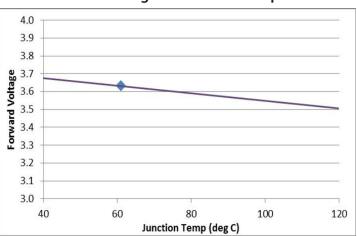
Peak Wavelength vs Junction Temperature



Forward Voltage vs Forward Current

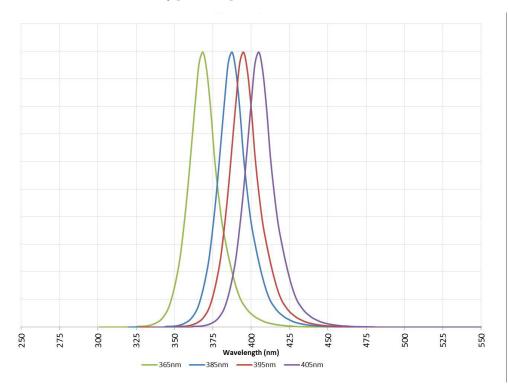


Forward Voltage vs Junction Temperature

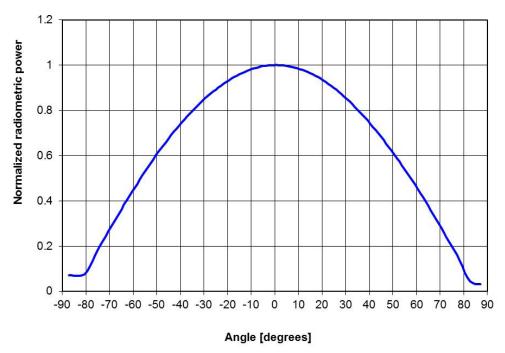




Typical Spectrum 12



Emission Angle 13

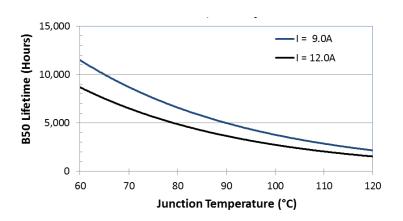


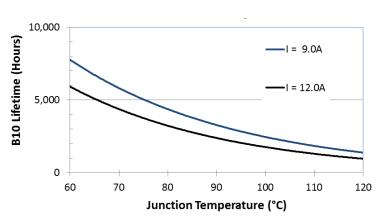
Note 12: Typical spectrum at current of 9 A in continuous operation.

Note 13: Detailed information on emission including ray trace files can be found at: http://www.luminus.com/resource/design.html

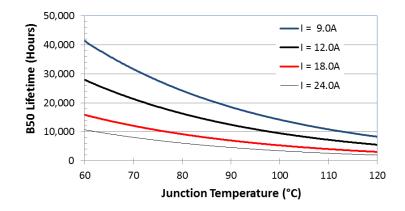


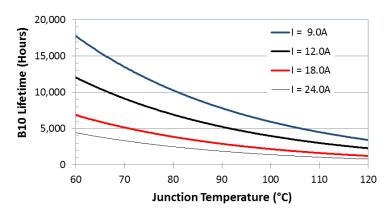
Reliability Data - 365nm





Reliability Data - 380nm-410nm







Thermal Resistance CBM-120-UV

T_J = Die Junction Temp TB = COREBOARD TEMP

Typical Thermal Resistance 14 - C31

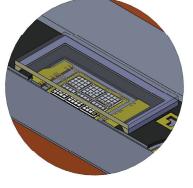
| $R_{\theta j-b}^{15}$ | 0.61 °C/W |
|------------------------|-----------|
| R _{0b-hs} 16 | 0.12 °C/W |
| R _{θj-hs} 16 | 0.73 °C/W |
| R _{θj-ref} 15 | 0.64 °C/W |

Ths = Heatsink Temp (3MM from surface)

Tref - Thermistor Temp

Typical Thermal Resistance 14 - C14

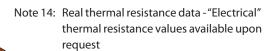
| R _{θj-b} ¹⁵ | 0.76 °C/W |
|---------------------------------|-----------|
| R _{0b-hs} 16 | 0.12 °C/W |
| $R_{\theta j-hs}^{16}$ | 0.88 °C/W |





TB = COREBOARD TEMP

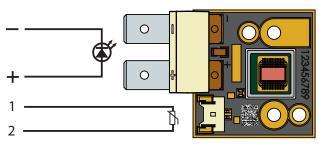
Ths = Heatsink Temp (3MM from surface)

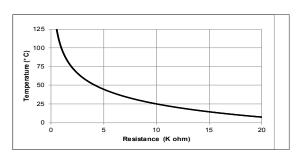


Note 15: Thermal resistance values are based on measured wavelength shift data.

Note 16: Thermal Resistance is based on eGraf 1205 Thermal interface.

Electrical Pinout - C31 Package



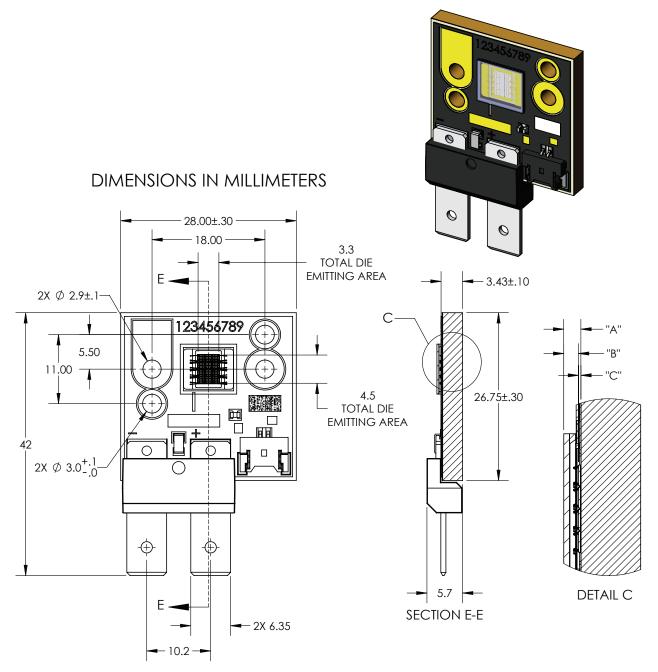


The thermistor used in CBT-120 devices mounted on coreboards is from Murata Manufacturing Co. The global part number is NCP18XH103J03RB. Please see http://www.murata.com/ for details on calculating thermistor temperature.

For more information on use of the thermistor, please contact Luminus directly.



Mechanical Dimensions - CBM-120-UV-C31 Mosaic Array LED Emitter



| DIMENSION NAME | DESCRIPTION | NOMINAL DIMENSION | TOLERANCE |
|-------------------|--|----------------------|-----------|
| "A" | TOP OF METAL SUBSTRATE TO TOP OF WINDOW | .91 | ±.13 |
| "B" | TOP OF DIE EMITTING AREA TO TOP OF WINDOW | .78 | ±.11 |
| "C" | TOP OF METAL SUBSTRATE TO TOP OF DIE EMITTING AREA | .13 | ±.02 |

DWG-002558

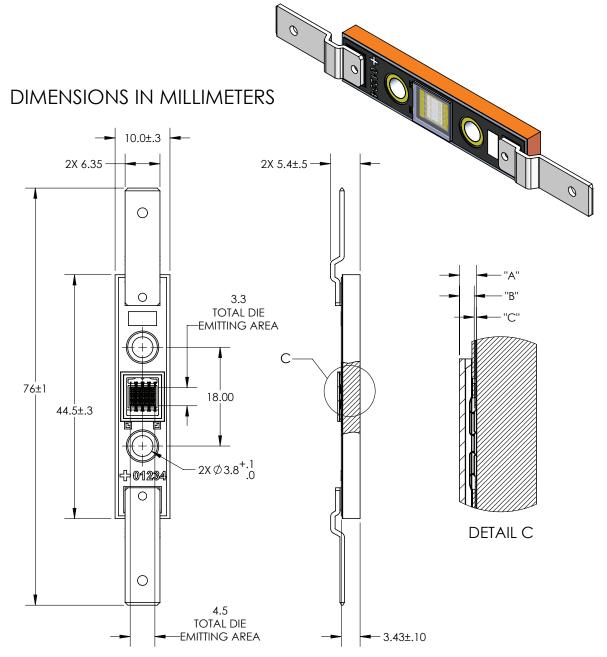
Recommended connector for Anode and Cathode: Panduit Disco Lok[™] Series P/N: DNG14-250FL-C. Thermistor Connector: MOLEX P/N 53780-0270 or GCT P/N WTB08-021S-F.

Recommended Female: MOLEX P/N 51146-0200, GCT P/N WTB06-021S-F or equivalent

175 New Boston Street • Woburn, MA 01801



Mechanical Dimensions - CBM-120-UV-C14 Mosaic Array LED Emitter



| DIMENSION NAME | DESCRIPTION | NOMINAL DIMENSION | TOLERANCE |
|-------------------|--|----------------------|-----------|
| "A" | TOP OF METAL SUBSTRATE TO TOP OF WINDOW | .91 | ±.13 |
| "B" | TOP OF DIE EMITTING AREA TO TOP OF WINDOW | .78 | ±.11 |
| "C" | TOP OF METAL SUBSTRATE TO TOP OF DIE EMITTING AREA | .13 | ±.02 |

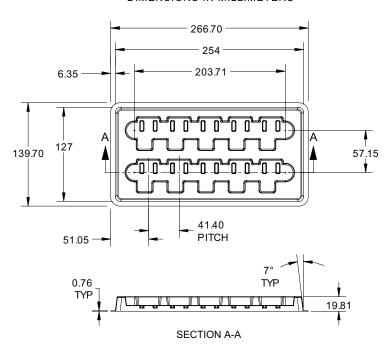
DWG-002534

Recommended connector for Anode and Cathode: Panduit Disco Lok™ Series P/N: DNG14-250FL-C.



Shipping Tray Outline - CBM-120-C31

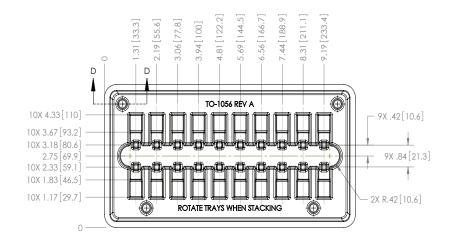
DIMENSIONS IN MILLIMETERS

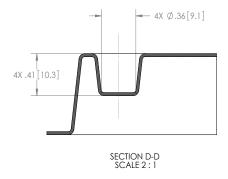


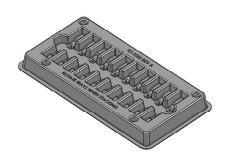




Shipping Tray Outline - CBM-120-C14









Packing and Shipping Specification (CBM-120)

Packing Specification

| Packing Configuration | Qty /Pack | Box Dimensions (diameter x W, mm) | Gross Weight (kg) |
|--|-----------|--------------------------------------|-------------------|
| Stack of 5 trays with 10 devices per tray Each pack is enclosed in ESD bag | 50 | 140 x 280 x 70 | 2.7 |

Product Label Specification

Label Fields (subject to change):

- 6-8 digit Box number (for Luminus internal use)
- Luminus ordering part number
- Quantity of devices in pack
- Part number revision (for Luminus internal use)
- Customer's part number (optional)
- Flux Bin
- 2D Bar code





Sample label –for illustration only

Shipping Box

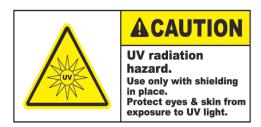
| Shipping Box | Quantity | Material | Dimensions (L x W x H, mm) |
|--------------|------------------------------------|----------|-------------------------------|
| Carton Box | 1 -20 packs (50 - 1000 Devices) | S4651 | 560 x 560 x 200 |





History of Changes

| Rev | | Description of Change |
|-----|------------|--|
| Α | 01/09/2015 | Initial Release - Preliminary Specifications for 365nm and 380nm CBM-120 Parts |
| В | 03/20/2015 | Added Data for 390nm and 400nm CBM-120 Parts, Updated binning structure |
| 01 | 05/31/2015 | Updated Binning, Added Angular Distribution Data, Added Reliability Data |
| | | |
| | | |



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